





SFC3005A Flip Chip Schottky Diode



Features

- Schottky diode for high-speed switching
- Case: WLCSP
- Very small dimensions:1.0mm*0.6mm*0.28mm
- 0.5A forward current
- Low forward voltage drop
- Low capacitance
- Low reverse current(<10uA @30V)

Circuit Diagram

Applications

- high efficiency DC/DC conversion
- fast switching
- protecting and clamping



Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	-	30	V
Average Rectified Forward Current	I _{F (AV)}	50/60Hz, sinus @Tc=25°C	0.5	Α
Peak One Cycle Non-Repetitive Surge Current	I _{FSM}	8.3ms, Half Sine pulse	5	А
Power dissipation	P _{tot}		450	mW

Electrical Characteristics:

Characteristics	Symbol	Condition	Тур.	Max.	Units
		IF=1mA	0.27	0.30	V
		IF=10mA	0.34	0.40	
Forward Voltage Drop *	V _F	IF=100mA	0.45	0.52	
		IF=200mA	0.53	0.60	
		IF=500mA	0.73	0.85	
		V _R = 5V	0.1	1	
Daviana Cumant*	I _R	V _R = 10V	0.2	2	uA
Reverse Current*		V _R = 30V	3	10	
		@T _J = 25 °C			
Junction Capacitance	Ст	$V_R = 5V$, $f_{SIG} = 1MHz$ $@T_C = 25 °C$	11	15	pF

^{*} Pulse width < 300 μ s, duty cycle < 2%

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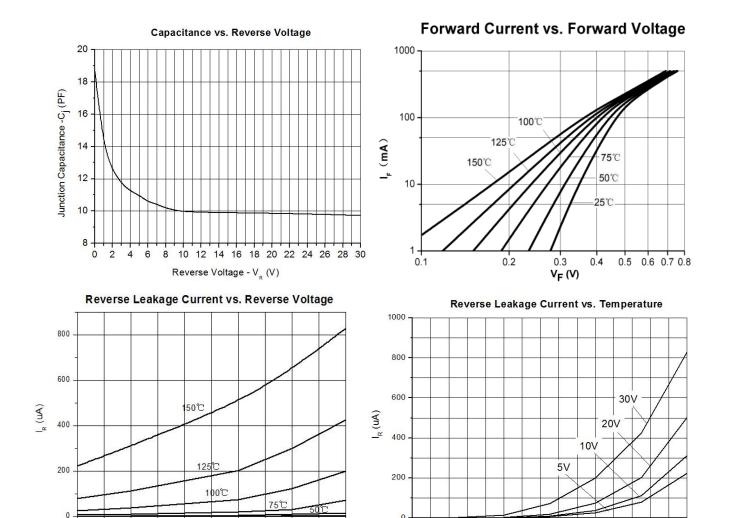


Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	150	°C
Storage Temperature	T _{stg}	-	-65 to +150	°C
Operating temperature range	T _{op}	-	-55 to +125	°C
Typical Thermal Resistance Junction to Ambient Air	R _{0JA}	DC operation	280	K/W

Ratings and Characteristics Curves

 $V_R(V)$



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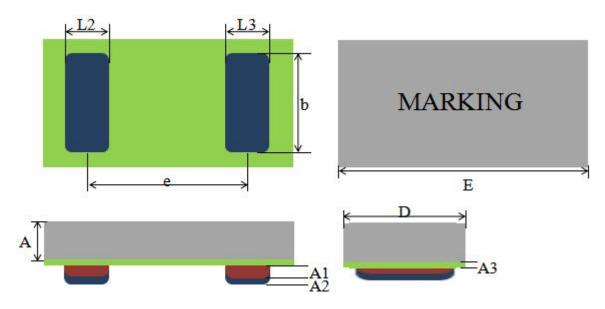


Ordering Information:

Device	Package	Plating	Shipping
SFC3005A	WLCSP	Cu+Sn	6000pcs/reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

Mechanical Dimensions (in millimeters:WLCSP)



ltem	Material	mechanical size(mm)			
		min	typ	max	
Α	Si	0.240	0.260	0.280	
A 1	Cu		0.008		
A2	Sn		0.003		
А3	PI	0.003	0.004	0.005	
b			0.500		
L2		0.200	0.250	0.300	
L3		0.200	0.250	0.300	
е			0.650		
D		0.590		0.63	
E		0.990		1.03	

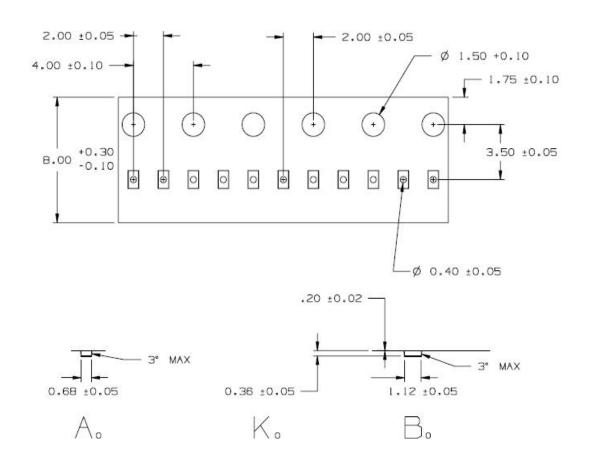
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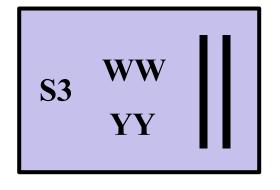




Carrier Tape and Reel Specification(in millimeters)



Marking Diagram



|| = cathode WW = week code YY = year code S3 = device code

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